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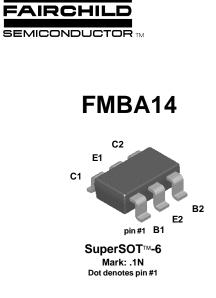
ON Semiconductor®

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FMBA14



NPN Multi-Chip Darlington Transistor

This device is designed for applications requiring extremely high current gain at collector currents to 1.0 A. Sourced from Process 05.

Absolute Maximum Ratings* $T_{a} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CES}	Collector-Emitter Voltage	30	V
V _{CBO}	Collector-Base Voltage	30	V
V _{EBO}	Emitter-Base Voltage	10	V
I _C	Collector Current - Continuous	1.2	А
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics $T_{a} = 25^{\circ}C$ unless otherwise noted

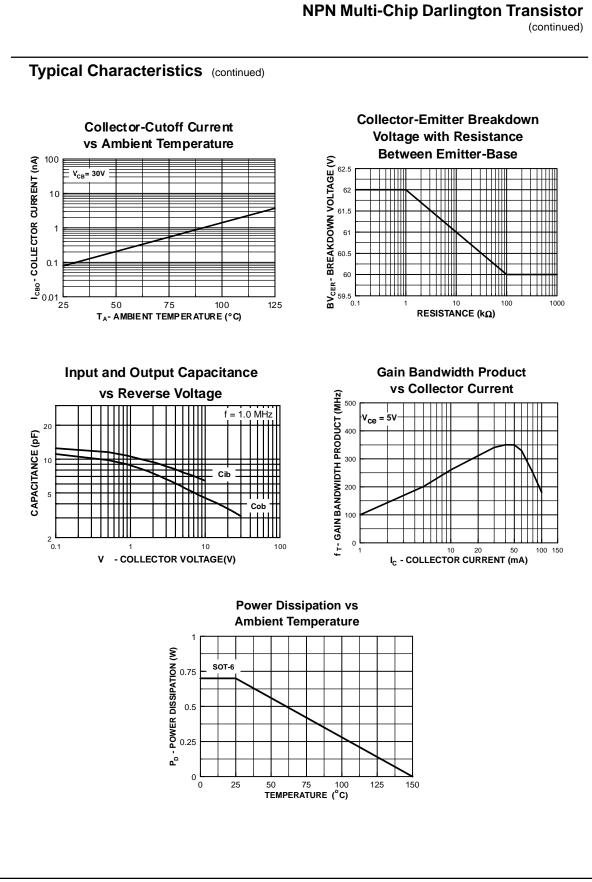
Symbol	Characteristic	Max	Units
		FMBA14	
PD	Total Device Dissipation	700	mW
	Derate above 25°C	5.6	mW/°C
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	180	°C/W

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FMBA14

NPN Multi-Chip Darlington Transistor (continued)						
Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
OFF CHAF	RACTERISTICS					<u> </u>
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	I _C = 100 μA, I _B = 0	30			V
I _{CBO}	Collector-Cutoff Current	$V_{CB} = 30 \text{ V}, \text{ I}_{E} = 0$			100	nA
I _{EBO}	Emitter-Cutoff Current	$V_{EB} = 10 \text{ V}, I_{C} = 0$			100	nA
ONCHAR	ACTERISTICS*					
h _{FE}	DC Current Gain	$I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	10K			
<u> </u>	Collector Emitter Octorstics Matte	$I_{C} = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}$	20K		4 5	
V _{CE(sat)}	Collector-Emitter Saturation Voltage Base-Emitter On Voltage	$I_{C} = 100 \text{ mA}, I_{B} = 0.1 \text{ mA}$ $I_{C} = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}$			1.5 2.0	V V
V _{BE(on)}	Base-Emilier On Vollage	1C = 100 IIIA, VCE = 3.0 V			2.0	v
SMALL SI	GNAL CHARACTERISTICS					
h _{fe}	Small Signal Current Gain	$I_{\rm C} = 10 \text{ mA}, V_{\rm CE} = 5.0 \text{ V},$	1.25			MHz
л.	Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%	f = 100 MHz	I		I	
ହୁ ଜୁ ଜୁ ଅନୁ 250 ୮୮	Al Characteristics Typical Pulsed Current Gain vs Collector Current V _{CE} = 5V 25 °C 0.01 C-40 °C 0.01 C- COLLECTOR CURRENT (A)	Collector-E Voltage vs 1.6 $\beta = 1000$ 1.2 $-40^{\circ}C$ $-40^{\circ}C$ $-40^{\circ}C$ 1.2 $-40^{\circ}C$ 1.2 $-40^{\circ}C$ 1.2 $-40^{\circ}C$ 1.2 $-40^{\circ}C$ 1.2 $-40^{\circ}C$		or Cur	rent	1000
V EBASE EMITTER VOLTAGE (V)	Base-Emitter Saturation Voltage vs Collector Current			rrent "C" V _{CE} 100	= 5V	1000

FMBA14



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